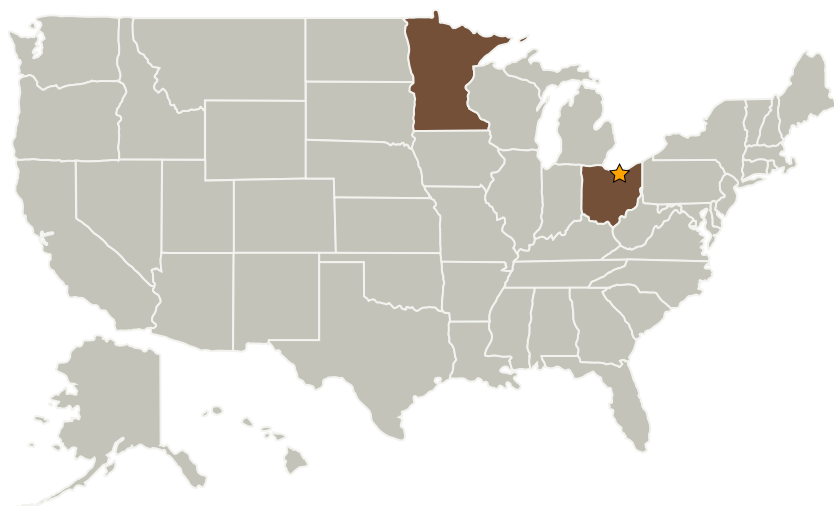


High-Frequency, Low-Noise Nitride-Based Power Transistors Grown on Bulk III-N, Phase II

Completed Technology Project (2003 - 2005)



Primary U.S. Work Locations and Key Partners



Organizations Performing Work	Role	Type	Location
★ Glenn Research Center(GRC)	Lead Organization	NASA Center	Cleveland, Ohio
SVT Associates	Supporting Organization	Industry	Eden Prairie, Minnesota

Primary U.S. Work Locations

Minnesota	Ohio
-----------	------



High-Frequency, Low-Noise
Nitride-Based Power Transistors
Grown on Bulk III-N, Phase II

Table of Contents

Primary U.S. Work Locations and Key Partners	1
Organizational Responsibility	1
Project Management	2
Technology Areas	2

Organizational Responsibility

Responsible Mission Directorate:

Space Technology Mission Directorate (STMD)

Lead Center / Facility:

Glenn Research Center (GRC)

Responsible Program:

Small Business Innovation Research/Small Business Tech Transfer

High-Frequency, Low-Noise Nitride-Based Power Transistors Grown on Bulk III-N, Phase II

Completed Technology Project (2003 - 2005)



Project Management

Program Director:

Jason L Kessler

Program Manager:

Carlos Torrez

Technology Areas

Primary:

- TX06 Human Health, Life Support, and Habitation Systems
 - └ TX06.3 Human Health and Performance
 - └ TX06.3.5 Food Production, Processing, and Preservation